
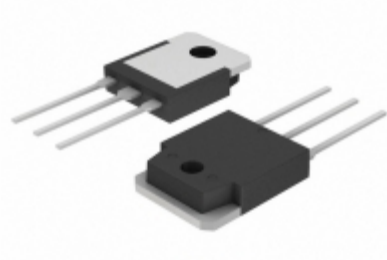
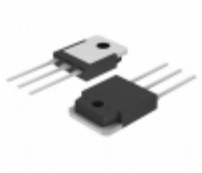
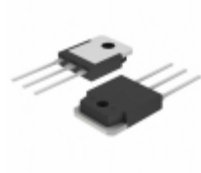
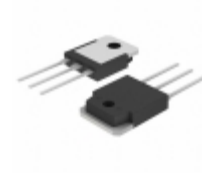
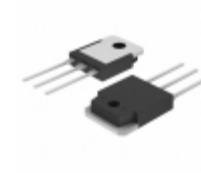
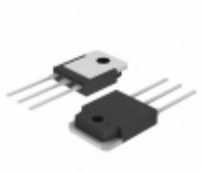

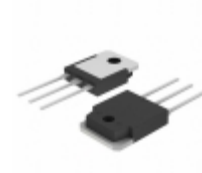
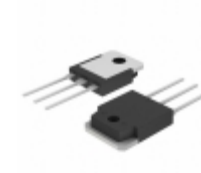
	<h2 style="color: red;">FQA10N80C</h2>
	<p>Hersteller-Teilenummer: FQA10N80C</p> <hr/> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <hr/> <p>Teil der Beschreibung: MOSFET N-CH 800V 10A TO-3P</p> <hr/> <p>Datenblätter:  FQA10N80C.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, 2184 pcs Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
 <p style="text-align: center;">Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FQA10N80C
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET N-CH 800V 10A TO-3P
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	2184 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-3P-3, SC-65-3
Supplier Device-Gehäuse	TO-3P
Verlustleistung (max)	240W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	800V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	10A (Tc)
Rds On (Max) @ Id, Vgs	1.1 Ohm @ 5A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	58nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	2800pF @ 25V
Verpackung	Tube













































FQA10N80C ist neu im Original, Suche FQA10N80C Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQA10N80C Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FQA10N80C: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQA10N80C-F109 AMI Semiconductor / ON Semiconductor MOSFET N-CH 800V 10A TO-3P</p>	 <p>FQA10N80_F109 Fairchild/ON Semiconductor MOSFET N-CH 800V 9.8A TO-3P</p>	 <p>FQA10N80C_F109 Fairchild/ON Semiconductor FQA10N80C_F109 Fairchild/ON Semiconductor</p>	 <p>FQA10N80 AMI Semiconductor / ON Semiconductor MOSFET N-CH 800V 9.8A TO-3P</p>
 <p>FQA10N80C AMI Semiconductor / ON Semiconductor MOSFET N-CH 800V 10A TO-3P</p>	 <p>FQA10N90 FSC FSC TO-3P</p>	 <p>FQA10N60C AMI Semiconductor / ON Semiconductor MOSFET N-CH 600V 10A TO-3P</p>	 <p>FQA10N80 Fairchild/ON Semiconductor MOSFET N-CH 800V 9.8A TO-3P</p>

heiße Teile

Mehr

 FQA10N60C	 FQA10N60C	 FQA10N80C	D FQA10N80C_F109	 FQA11N90
 FQA11N90	 FQA11N90C	D FQA11N90C	 FQA11N90C	 FQA11N90C_F109
 FQA11N90_F109	 FQA12N60C	 FQA12P20	 FQA12P20	 FQA13N50
D FQA13N50	 FQA13N50C	 FQA13N50C	 FQA13N50C_F109	 FQA13N80
 FQA13N80	 FQA13N80_F109	 FQA140N10	 FQA140N10	 FQA14N30
 FQA14N30	 FQA160N08	D FQA160N08	 FQA16N50	 FQA16N50
 FQA170N06	D FQA170N06	 FQA18N40	 FQA18N50	 FQA19N20C
 FQA19N20C	 FQA19N20L	 FQA19N20L	 FQA19N60	 FQA19N60
 FQA20N40	 FQA20N40	 FQA20N50	D FQA20N60	 FQA20N80
 FQA24N50	 FQA24N50	 FQA24N50F	 FQA24N50F	 FQA24N60

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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